

BC447, BC449, BC449A

High Voltage Transistors

PNP Silicon



ON Semiconductor™

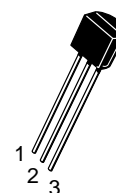
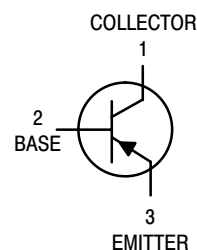
<http://onsemi.com>

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC447 BC449, BC449A	V_{CEO}	80 100	Vdc
Collector-Base Voltage BC447 BC449, BC449A	V_{CBO}	80 100	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	Vdc
Collector Current – Continuous	I_C	300	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$
Moisture Sensitivity Level (MSL) Electrostatic Discharge (ESD)		MSL: 1 NA	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$



CASE 29
TO-92
STYLE 17

MARKING DIAGRAM



BC44xx = Specific Device Code
xx = 7, 9 or 9A
Y = Year
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
BC447	TO-92	5000 Units/Box
BC449	TO-92	5000 Units/Box
BC449A	TO-92	5000 Units/Box

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (Note 1.) (I _C = 1.0 mA _{dc} , I _B = 0)	V _{(BR)CEO}	80 100	– –	– –	V _{dc}
Collector–Base Breakdown Voltage (I _C = 100 μA _{dc} , I _E = 0)	V _{(BR)CBO}	80 100	– –	– –	V _{dc}
Emitter–Base Breakdown Voltage (I _E = 10 μA _{dc} , I _C = 0)	V _{(BR)EBO}	5.0	–	–	V _{dc}
Collector Cutoff Current (V _{CB} = 60 V _{dc} , I _E = 0) (V _{CB} = 80 V _{dc} , I _E = 0)	I _{CBO}	– –	– –	100 100	nA _{dc}
ON CHARACTERISTICS (Note 1.)					
DC Current Gain (I _C = 2.0 mA _{dc} , V _{CE} = 5.0 V _{dc}) (I _C = 10 mA _{dc} , V _{CE} = 5.0 V _{dc}) (I _C = 100 mA _{dc} , V _{CE} = 5.0 V _{dc})	h _{FE}	50 120 50 100 50 60	– – – – – –	460 220 – – – –	–
Collector–Emitter Saturation Voltage (I _C = 100 mA _{dc} , I _B = 10 mA _{dc})	V _{CE(sat)}	–	0.125	0.25	V _{dc}
Base–Emitter Saturation Voltage (I _C = 100 mA _{dc} , I _B = 10 mA _{dc})	V _{BE(sat)}	–	0.85	–	V _{dc}
Base–Emitter On Voltage (I _C = 2.0 mA _{dc} , V _{CE} = 5.0 V _{dc}) (I _C = 100 mA _{dc} , V _{CE} = 5.0 V _{dc}) (Note 1.)	V _{BE(on)}	0.55 –	– 0.76	0.7 1.2	V _{dc}
DYNAMIC CHARACTERISTICS					
Current–Gain – Bandwidth Product (I _C = 50 mA _{dc} , V _{CE} = 5.0 V _{dc} , f = 100 MHz)	f _T	100	200	–	MHz

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle 2%

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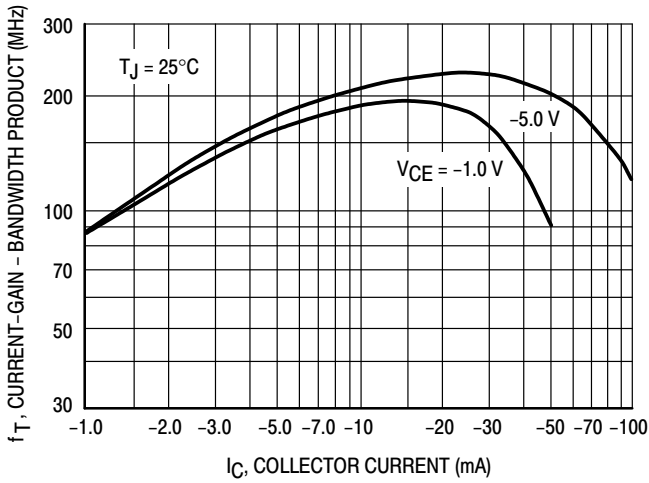


Figure 1. Current-Gain — Bandwidth Product

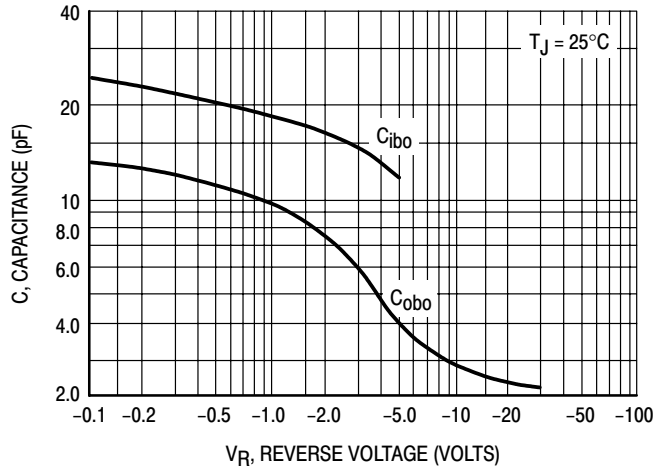


Figure 2. Capacitance

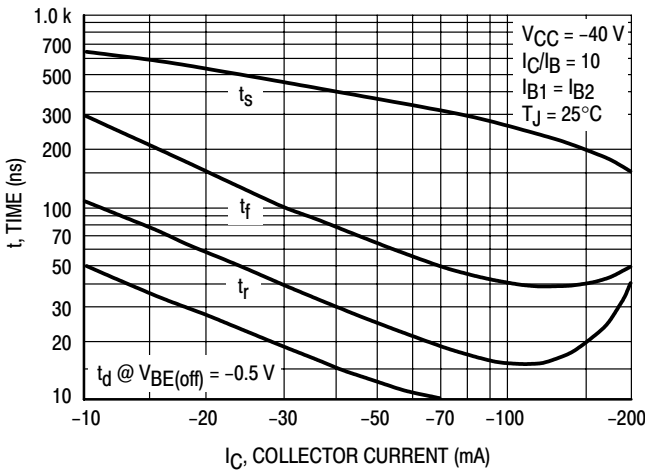


Figure 3. Switching Times

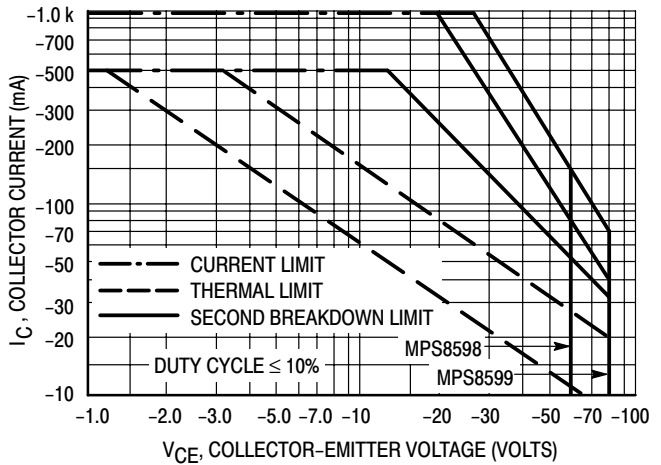


Figure 4. Active-Region Safe Operating Area

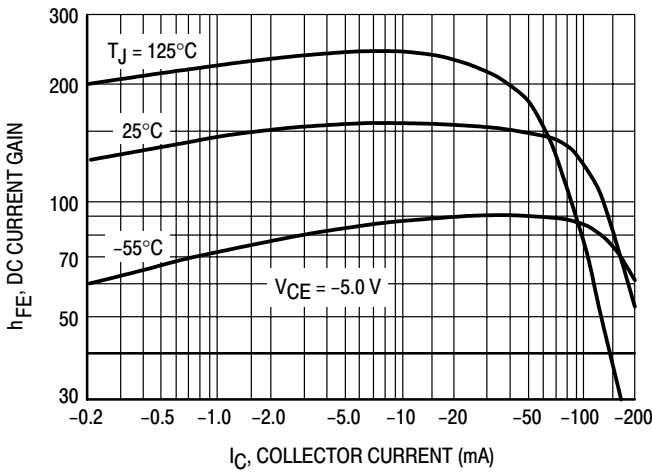


Figure 5. DC Current Gain

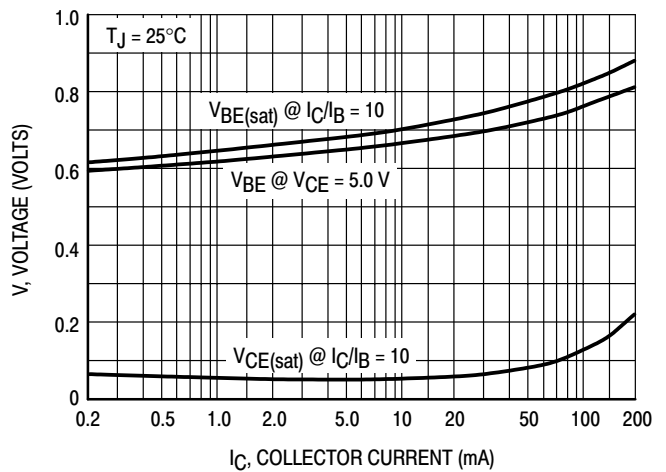


Figure 6. "ON" Voltages

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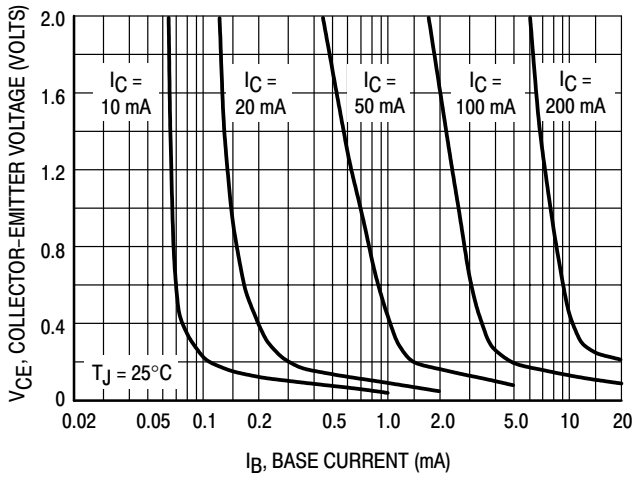


Figure 7. Collector Saturation Region

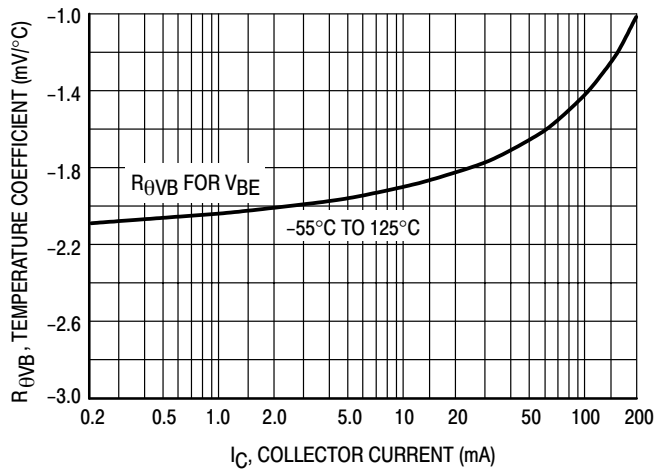


Figure 8. Base-Emitter Temperature Coefficient

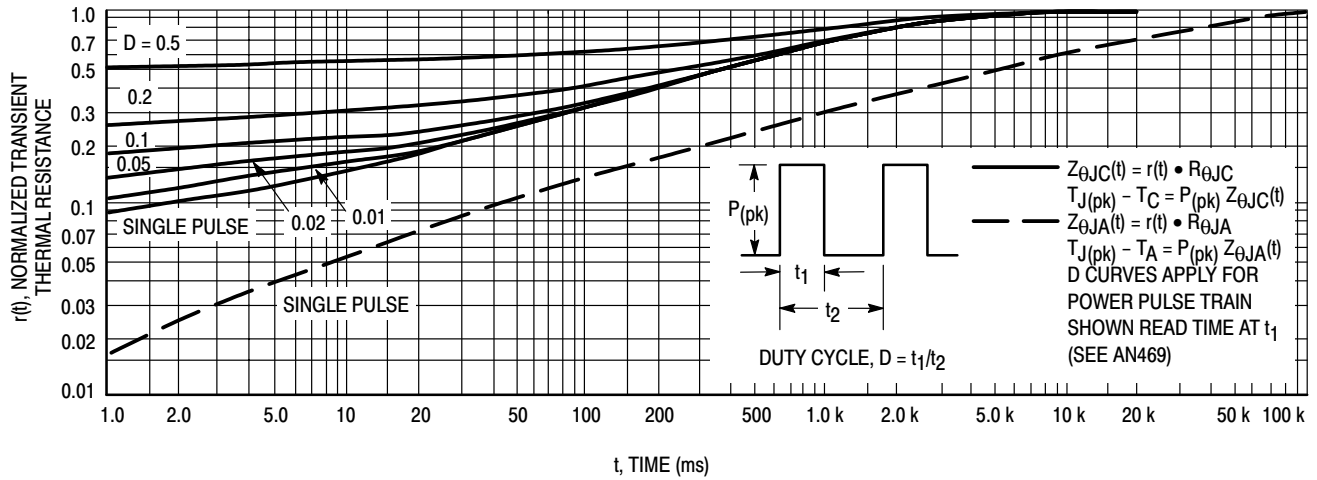
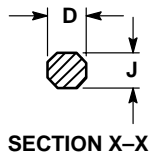
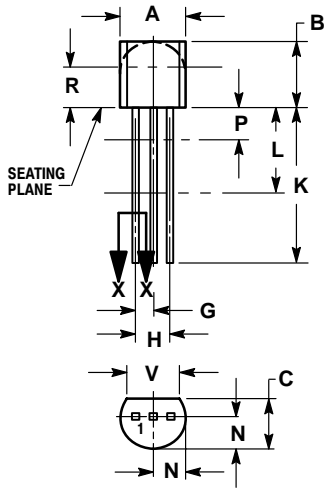


Figure 9. Thermal Response

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PACKAGE DIMENSIONS

TO-92
(TO-226)
CASE 29-11
ISSUE AL



NOTES:


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 17:
PIN 1. COLLECTOR
2. BASE
3. EMITTER

Notes

Notes

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